

# SANYO Semiconductors DATA SHEET

An ON Semiconductor Company

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# LV56351JA — 1ch DC/DC boost converter

#### **Overview**

LV56351JA integrates 1ch DC/DC boost converter and 1ch LDO. It is suitable as the power supply for BS/CS antennas of LCD/PDP TV and BD recorders that require automatic recovery without IC destruction and malfunction when the output is short-circuited.

#### Functions

DC/DC boost converter

- Soft-start time: 2.8ms
- Frequency 425kHz operation
- Pulse by pulse over current limiter
- Short circuit protector (SCP)

#### LDO

- Over current limiter (Fold back)
- All
- Under voltage lockout
- Thermal shutdown protector
- Power good

#### Specifications Maximum Ratings at Ta = 25°C

Parameter		Symbol	Conditions	Ratings
V <sub>CC</sub> maximum supply voltage V <sub>CC</sub>		V <sub>CC</sub> max		-0.3 to 25
LDOIN maximum input voltage VLC		VLDOIN		-0.3 to 30
SW maximum voltage		V <sub>SW</sub>		-0.3 to 30
Allowable power dissipation		Pd max	*1	1.1
Operating temperature		Topr		-30 to 85
Operating junction temperature		Tjopr		-30 to 125
Storage temperature		Tstg		-40 to 150
Allowable V <sub>CC</sub> , EN				25
pin voltage	SW, LDOIN, LDOOUT			30
	IN1, IN2, FB, SCP, PGOOD, DDCTL			6

\*1: When mounted on the specified printed circuit board (32mm × 38mm × 1.6mm), glass epoxy, double side board

Caution 1) Absolute maximum ratings represent the value which cannot be exceeded for any length of time.

Caution 2) Even when the device is used within the range of absolute maximum ratings, as a result of continuous usage under high temperature, high current, high voltage, or drastic temperature change, the reliability of the IC may be degraded. Please contact us for the further details.

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# LV56351JA

#### Recommended Operating Conditions at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
V <sub>CC</sub> supply voltage	V <sub>CC</sub>		8 to 23	V
LDOIN input voltage	V <sub>LDOIN</sub>		8 to 28	V
SW voltage	V <sub>SW</sub>		-0.3 to 28	V
EN voltage	V <sub>EN</sub>		0 to 23	V

## **Electrical Characteristics** at Ta = 25°C, $V_{CC}$ = 12V, $V_{EN}$ =2V, LDOIN=16V, LDOOUT=15V

Deremeter	Symbol	Conditions	Ratings			1114
Parameter			min	typ	max	Unit
All						
Supply current	ICC	Switching is turned off		1.8	3.5	mA
	IOFF	EN=0V			10	μA
Reference voltage	VREF		1.2348	1.26	1.2852	V
Enable voltage	V <sub>EN</sub>		2.0			V
Disable voltage	V <sub>DIS</sub>				0.4	V
EN input current	IEN	V <sub>EN</sub> =2.0V			10	μA
PGOOD threshold	V <sub>PG</sub>	IN1≥VREF×85% and IN2≥VREF×85%		VREF×0.85		V
PGOOD sink current	IPG	V <sub>PGOOD</sub> =0.5V		1.0		mA
PGOOD leak current	I <sub>PGLK</sub>	V <sub>PGOOD</sub> =2V			10	μA
UVLO on voltage	VUVLO			7.0		V
Thermal shutdown temperature	T <sub>TSD</sub>	*2	130			°C
TSD hysteresis	THYS	*2		30		°C
DC/DC boost converter						
FB output voltage "Low"	FBLOW	IN1=2.0V, I <sub>FB</sub> =-20µA (Sink)			0.2	V
FB output voltage "High"	FBHIGH	IN1=0.2V, I <sub>FB</sub> =20µA (Sink)	1.8			V
Soft-start time	T <sub>SS</sub>			2.8		ms
Oscillator frequency	Fosc			425		kHz
Max on duty	D <sub>MAX</sub>		78	85	92	%
SW on resistance	R <sub>ON</sub>			0.7		Ω
SW peak current	IРК		1.5	1.8		А
SCP source current	ISCP			4.8		μA
SCP threshold	V <sub>SCP</sub>			VREF		V
DDCTL on voltage	VDDCTLON	DC/DC OFF	2.0			V
DDCTL off voltage	VDDCTLOFF	DC/DC ON			0.4	V
DDCTL input current	IDDCTL	V <sub>DDCTL</sub> =2V			20	μA
LDO						
Maximum output current	IOMAX		350	520	670	mA
Line regulation	R <sub>LN</sub>	16V <ldoin<21v< td=""><td></td><td></td><td>20</td><td>mV</td></ldoin<21v<>			20	mV
Load regulation	R <sub>LD</sub>	10mA <i<sub>O&lt;300mA</i<sub>			20	mV
Dropout voltage	VDROP	I <sub>O</sub> =300mA		0.25	0.4	V
Short current	ISHORT	LDOOUT=GND			100	mA

\*2: Design guarantee value.

#### Package Dimensions

unit : mm (typ) 3179C



**Specified board** (32×38×1.6mm<sup>3</sup>, glass epoxy, double side board)



« front »

« back »

# Pin assignment

1 🗆	PGND	PGND 🗖 20
2 🗆	NC	PGND 🗖 19
3 🗆	NC	NC 🗖 18
4 🗆	LDOOUT	SW 🗖 17
5 🗆	LDOIN	NC 🗖 16
6 🗆	NC	V <sub>CC</sub> 🗖 15
7 🗆	IN2	EN 🗖 14
8 🗆	IN1	DDCTL 🗖 13
9 🗆	FB	SCP 🗖 12
10 🗆	SGND	PGOOD 🗖 11

Pin function					
Pin No.	Pin name	Function	Equivalent circuit		
4	LDOOUT	LDO output			
5	LDOIN	LDO input			
10	SGND	Signal ground(*3)			
			(10) SGND		
			Ŭ		
7	IN2	LDO feedback input	$(\downarrow)$		
			SGND (10) • • • • •		
8	IN1	DC/DC error amplifier input	$\bigcirc$		
			SGND (10)		
9	FB	DC/DC error amplifier output	$\rightarrow$		
			FB (9) + W + F		
			SGND (10) + + + + + +		
11	PGOOD	Power good output			
			500Ω ≩		
			10 SGND		
12	SCP	DC/DC SCP capacitor connect on for timer setting			
12			🕀 300Ω 2kΩ 👝		
			(12) SCP		
13	DDCTL	DC/DC on and off control			
14	EN	Enable Power supply	V <sub>CC</sub> (15)		
10	VCC	Fower suppry			
1					

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Pin No.	Pin name	Function	Equivalent circuit
17	SW	DC/DC open drain output	VREG
1	PGND	Power ground(*3)	17) SW
19			
20			-  <b>-</b>

\*3: When you use this IC, Please short-circuit all the pins of SGND and PGND on the IC mounting side.

#### **Function overview**

(1) UVLO (Under Voltage Lockout)

UVLO stops outputs of both DC/DC and LDO to prevent malfunction when  $V_{CC}$  decreases. UVLO operates when  $V_{CC}$  falls below the UVLO voltage. This function is a non-latch-type, and recovers these outputs automatically when  $V_{CC}$  exceeds the UVLO voltage.

(2) Power good

Power good notifies that the output voltages of DC/DC and LDO are within the range of the setting voltage. The two output voltages are monitored through the voltage of IN1 and IN2. The output is judged to be "power good" when both outputs are 85% or higher compared to the setting voltages. If either IN1 or IN2 voltage falls below VREF×85%, PGOOD output becomes  $L \rightarrow H$  (No Good). When IN1 and IN2 voltages become (VREF×85%) + 30mV or higher, PGOOD output becomes  $H \rightarrow L$  (Good). During soft start, the output is H (No Good).

« Power good circuit diagram »



(3) Pulse-by-Pulse over current protection (P by P)

The P by P stops switch-on operation of a certain cycle by force when the current of power MOSFET reaches the maximum output peak current.

« P by P circuit diagram »



(4) Short Circuit Protector (SCP)

When output voltage of DC/DC decreases due to short-circuit; for example, SCP latches off the outputs of DC/DC and LDO by timer.

When output voltage of DC/DC decreases and FB turns to H, which is the error amplifier output, charge at  $4.8\mu$ A constant current starts to SCP capacitor for timer setting. When SCP voltage exceeds the threshold voltage (=VREF), latch-off occurs. If the output voltage recovers until the time the SCP voltage reaches to the threshold voltage, SCP capacitor is discharged and timer is reset. To restart the output after latch-off, you need to input EN signal again. If you do not use the SCP function, make sure to short SCP and GND.

To define timer, you need to calculate a value of SCP capacitor using the following formula because timer (tSCP) depends on capacitance.

$$CSCP = (I_{SCP} \times tSCP) / VREF$$



(5) DC/DC on and off control

This function controls on and off of DC/DC during the operation of IC.

« Turning on DC/DC »

Where DDCTL=Low or open, DC/DC and LDO operate at the same time.

« Turning off DC/DC »

Where DDCTL=High, DC/DC is compulsorily stopped and only LDO operates. When DDCTL is switched from H to L (or open), LDO stops temporarily and DC/DC starts with soft start and then LDO restart. If you switch DDCTL during IC operation, make sure that the output waveforms of DC/DC and LDO are normal.

#### **Output voltage setting**

Output voltages are given by the following formulas.  $DCDCOUT = (1+R2/R1) \times VREF [V]$ 

LDOOUT =  $(1+R4/R3) \times VREF[V]$ 

« Resistance for output setting »



#### Start and stop

Start: Make sure to input EN signal (L  $\rightarrow$  H) after supplying V<sub>CC</sub>=12V. Stop: Reverse-operation of start.

« Output waveform during start and stop »



#### Block Diagram and Application circuit 1 (for BS antenna)

Condition: V<sub>CC</sub>=12V, DCDCOUT=16V, LDOOUT=15V



« Note »

When LDOOUT is in the over current state or the short-circuit state, IC and external parts are protected by over current limiter of LDO. And when DCDCOUT is short-circuited, IC stops by timer latch-off type SCP function.

### Application circuit 2 (for BS/CS antenna)

BS condition: V<sub>CC</sub>=12V, DCDCOUT=16V, LDOOUT=15V CS condition: V<sub>CC</sub>=12V, DCDC=OFF, LDOOUT=11V



5ms

DC/DC OUT

LDOOUT

Time

« Addition »

The above application circuit enables switching between 15V for BS and 11V for CS. Where DDCTL=L, DC/DC booster is turned on and set as follows: DCDCOUT=16V, LDOOUT=15V. Where DDCTL=H, DC/DC booster is turned off and set as follows: DCDCOUT=11.7V, LDOOUT=11V. (because the resistance value of output setting of LDO is switched)

#### « Output waveform at switching » LDOOUT=15V $\rightarrow$ 11V

16V

15V

11V

DDCTL

12V(=VCC)



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